

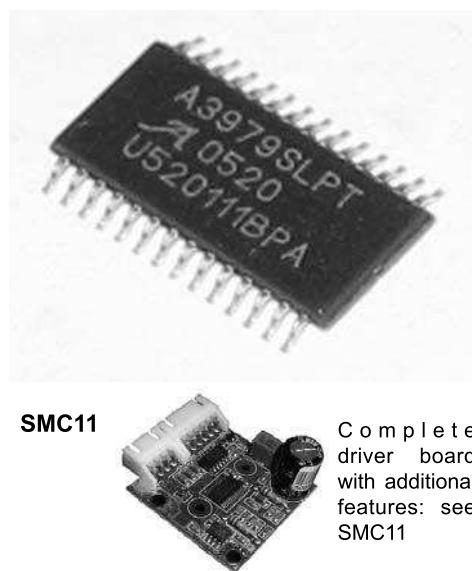
IMT-903 Microstep driver

(Allegro A3979SLP - T)

The IMT-903 provides maximum functional and power density with the least power loss with < 0.7 cm².

Advantages:

- Just 1 IC for power and logic up to 2.5 A and 35V provides maximum space and cost reduction with little external circuitry
- Microstep up to 1/16 provides quiet and even running behaviour and also reduces system resonance
- Automatic decay switchover (slow, mixed and fast) reduces power loss and motor noise considerably, and also increases step accuracy
- Extremely safe operation due to integrated overcurrent protection, undervoltage detection and crossover current protection



Complete driver board with additional features: see SMC11

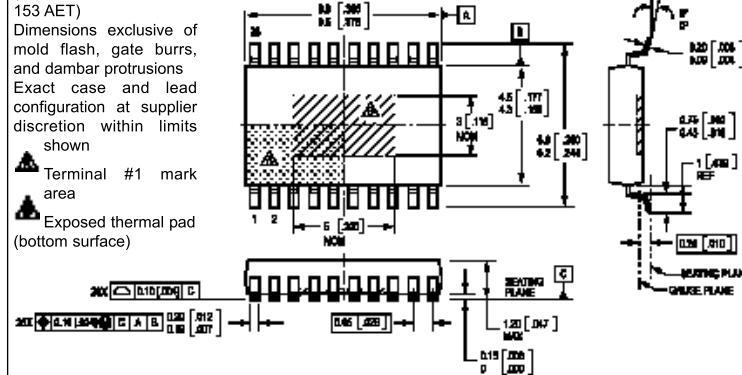
Complete information on the Internet:
www.nanotec.de

Dimensioned diagram (mm)

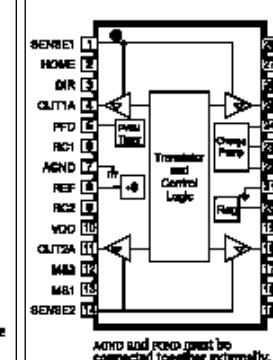
Dimensions in brackets =
in
(reference JEDEC MO-153 AET)

Dimensions exclusive of
mold flash, gate burrs,
and dambar protrusions
Exact case and lead
configuration at supplier
discretion within limits
shown

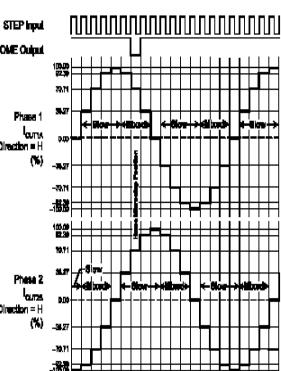
Terminal #1 mark area
 Exposed thermal pad
(bottom surface)



PIN assignments



Quarter step operation



Electrical characteristics

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V_{DD} = 35\text{ V}$, $V_{DD} = 3.0\text{ to }5.5\text{ V}$ (unless otherwise noted)

Characteristics	Symbol	Test Conditions	Min.	Typ. ¹	Max.	Units
Output Drivers						
Load Supply Voltage Range	V_{DD}	Operating	5	—	35	V
		During Sleep mode	0	—	35	V
Output Leakage Current ²	I_{OSS}	$V_{DD} = V_{SS}$	—	<1.0	20	μA
		$V_{DD} = 0\text{ V}$	—	<1.0	20	μA
Output On Resistance	$R_{DS(on)}$	Source driver, $I_{DS} = 2.6\text{ A}$	—	0.28	0.356	Ω
		Source driver, $I_{DS} = 2.5\text{ A}$	—	0.22	0.295	Ω
Body Diode Forward Voltage	V_F	Source diode, $I_F = 2.6\text{ A}$	—	—	14	V
		Sink diode, $I_F = 2.5\text{ A}$	—	—	8.0	mA
Motor Supply Current	I_M	$f_{MOT} < 60\text{ kHz}$	—	—	8.0	mA
		Operating, outputs disabled	—	—	8.0	mA
		Sleep mode	—	—	20	μA
Control Logic						
Logic Supply Voltage Range	V_{DD}	Operating	3.0	5.0	5.5	V
		$f_{MOT} < 60\text{ kHz}$	—	—	12	mA
Logic Supply Current	I_{DD}	Outputs off	—	—	10	mA
		Sleep mode	—	—	20	μA
Logic Input Voltage	$V_{IN(H)}$	$0.7 \times V_{DD}$	—	—	V	
	$V_{IN(D)}$	—	—	$0.3 \times V_{DD}$	V	
Logic Input Current ³	$I_{IN(H)}$	$V_{IN} = 0.7 \times V_{DD}$	-20	<1.0	20	μA
	$I_{IN(D)}$	$V_{IN} = 0.3 \times V_{DD}$	-20	<1.0	20	μA
Reference Input Voltage Range	V_{REF}	Operating	0	—	V_{DD}	V
Reference Input Current	I_{REF}	—	0	± 5	μA	
HOME Output Voltage	$V_{HOME(H)}$	$I_{HOME} = -200\text{ }\mu\text{A}$	$0.7 \times V_{DD}$	—	—	V
	$V_{HOME(D)}$	$I_{HOME} = 200\text{ }\mu\text{A}$	—	—	$0.3 \times V_{DD}$	V
Mixed Decay Mode Trip Point	V_{TRIP}	—	—	$0.8 \times V_{DD}$	—	V
	V_{REFD}	—	—	$0.21 \times V_{DD}$	—	V
Gain (G_m) Error ⁴	G_m	$V_{DD} = 2\text{ V}$, Phase Current = 36.27%	—	—	± 10	%
		$V_{DD} = 2\text{ V}$, Phase Current = 70.71%	—	—	± 5.0	%
		$V_{DD} = 2\text{ V}$, Phase Current = 100.00%	—	—	± 5.0	%
STEP Pulse Width	t_W	—	1	—	—	μs
Blank Time	t_{BLANK}	$R_T = 56\text{ k}\Omega$, $C_T = 650\text{ pF}$	700	950	1200	ns
Fixed Off-Time	t_{OFF}	$R_T = 56\text{ k}\Omega$, $C_T = 650\text{ pF}$	30	36	46	μs
Crossover Dead Time	t_{CR}	Synchronous rectification enabled	100	475	500	ns
Thermal Shutdown Temperature	T_{SD}	—	—	165	—	$^\circ\text{C}$
Thermal Shutdown Hysteresis	T_{SDH}	—	—	15	—	$^\circ\text{C}$
UVLO Enable Threshold	V_{UVLO}	Increasing V_{DD}	2.45	2.7	2.95	V
UVLO Hysteresis	V_{UVLOH}	—	0.05	0.10	—	V

Block diagram

